

40V SURFACE MOUNT SCHOTTKY BARRIER DIODE
Product Summary

- $V_R = 40V$
- $I_F = 0.52A$
- $I_R = 10\mu A$

Description and Applications

This compact SOD323 packaged Schottky diode offers users an excellent performance combination comprising high current operation, extremely low leakage and low forward voltage ensuring suitability for applications requiring efficient operation at higher temperatures (above 85°C) see Operational efficiency chart on page 4.

- DC – DC Converters
- Mobile Telecomms
- Charging circuits
- Motor control

Features and Benefits

- Low Equivalent On Resistance
- Extremely low leakage ($10\mu A @ 30V$)
- High current capability ($I_F = 0.52A$)
- Low V_F , fast switching Schottky
- ZLLS400 complements low temperature equivalent ZHCS400
- Package thermally rated to 150°C
- **Qualified to AEC-Q101 Standards for High Reliability**

Mechanical Data

- Case: SOD323
- Case Material: UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections: Cathode Band
- Terminals: Finish - Matte Tin annealed over Alloy 42 leadframe. Solderable per MIL-STD-202, Method 208
- Weight: 0.004 grams (approximate)

SOD323

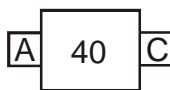


Top View

Ordering Information (Note 1)

Device	Packaging	Shipping
ZLLS400TA	SOD323	3,000/Tape & Reel
ZLLS400TC	SOD323	10,000/Tape & Reel

Notes: 1. For Packaging Details, go to our website at <http://www.diodes.com>.

Marking Information


40 = Product Type Marking Code

Top View

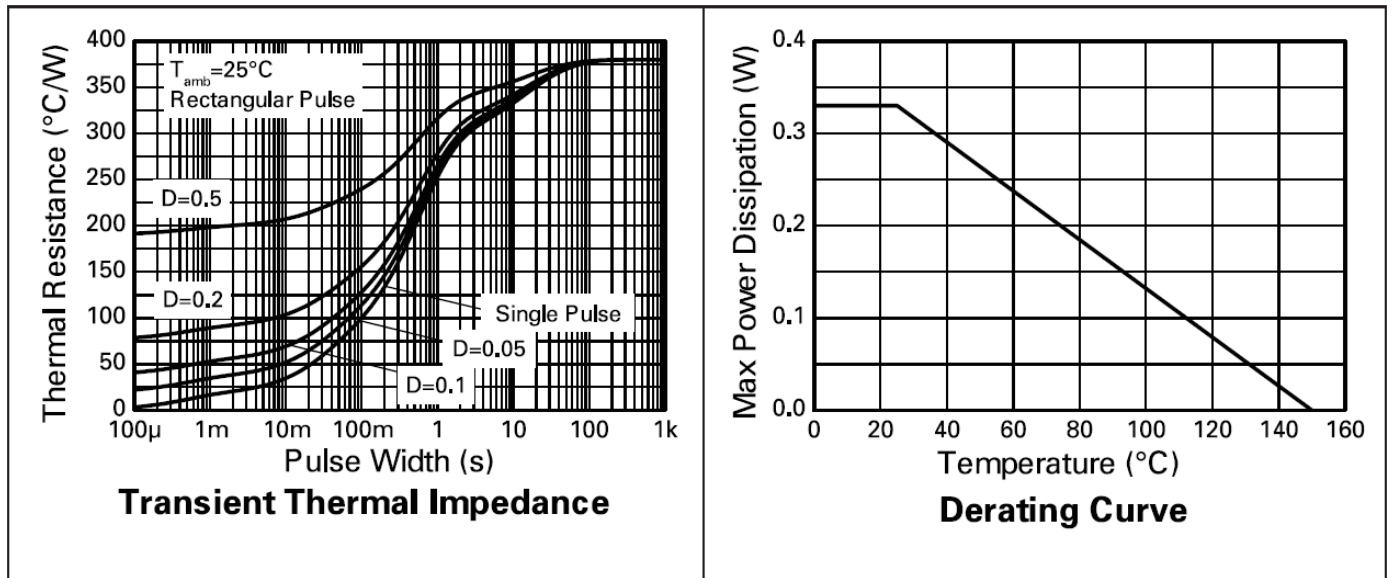
Maximum Ratings @ $T_A = 25^\circ\text{C}$ unless otherwise specified

Characteristic	Symbol	Value	Units
Continuous Reverse Voltage	V_R	40	V
Continuous Forward Current	I_F	0.52	A
Peak Repetitive Forward Current Rectangular Pulse Duty Cycle	I_{FPK}	0.85	A
Non Repetitive Forward Current		$t \leq 100\mu\text{s}$	12
		$t \leq 10\text{ms}$	2.5

Thermal Characteristics

Characteristic	Symbol	Value	Unit
Power Dissipation, $T_A = 25^\circ\text{C}$ Single Die Continuous Single Die Measured at $t < 5$ secs	P_D	330 390	mW
Thermal Resistance, Junction to Ambient	$R_{\theta JA}$	379 317	$^\circ\text{C}/\text{W}$
Junction Temperature	T_J	150	$^\circ\text{C}$
Storage Temperature Range	T_{STG}	-55 to +150	$^\circ\text{C}$

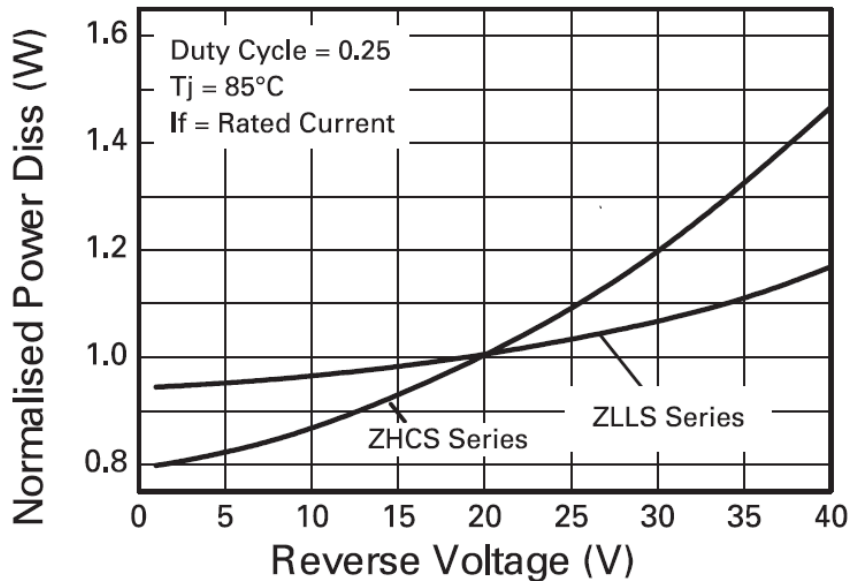
Notes: 2. For a device surface mounted on 25mm x 25mm FR4 PCB with high coverage of single sided 1oz copper, in still air conditions.
3. For a device surface mounted on FR4 PCB measured at $t < 5$ secs.



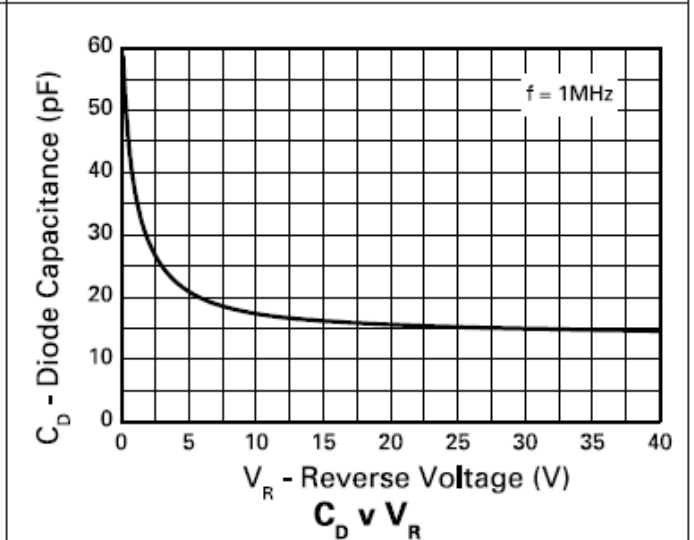
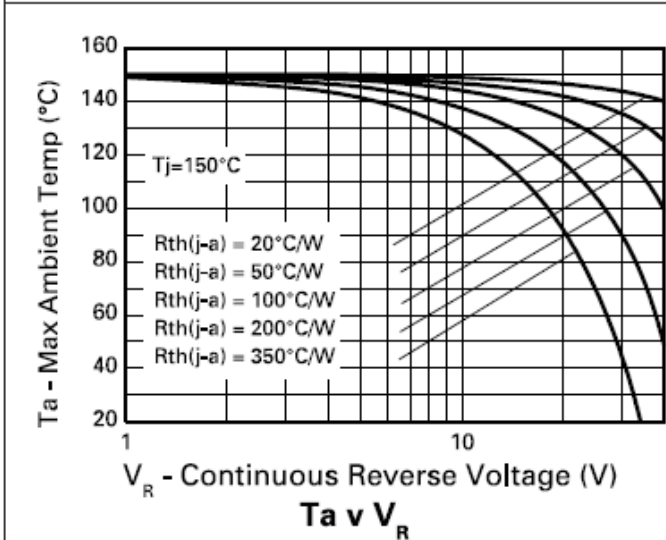
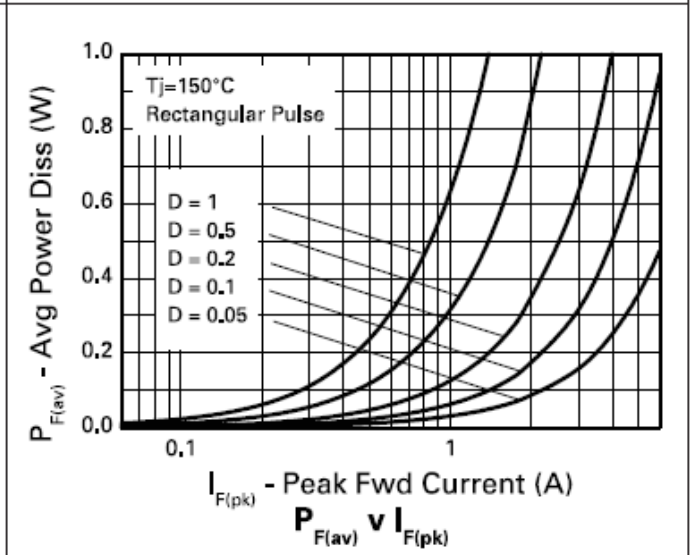
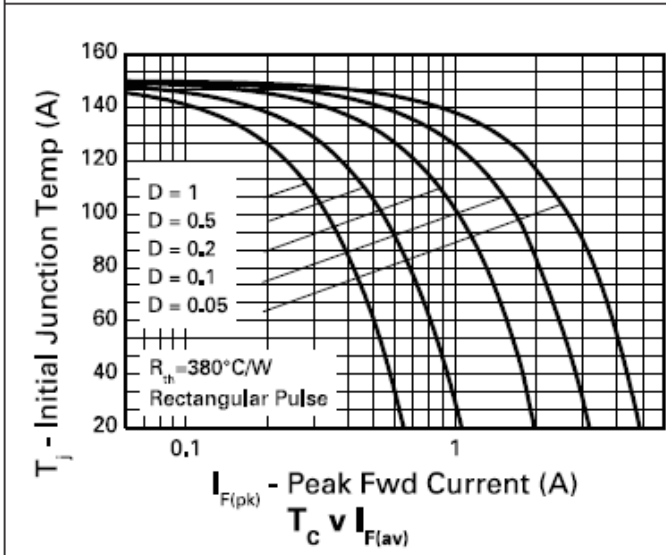
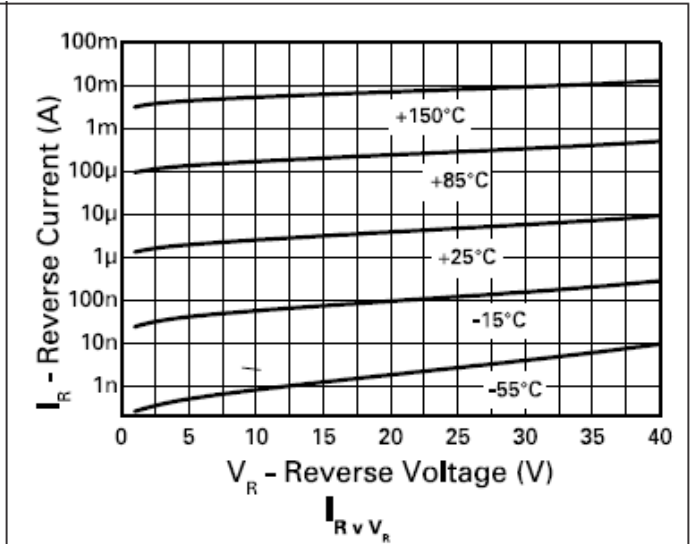
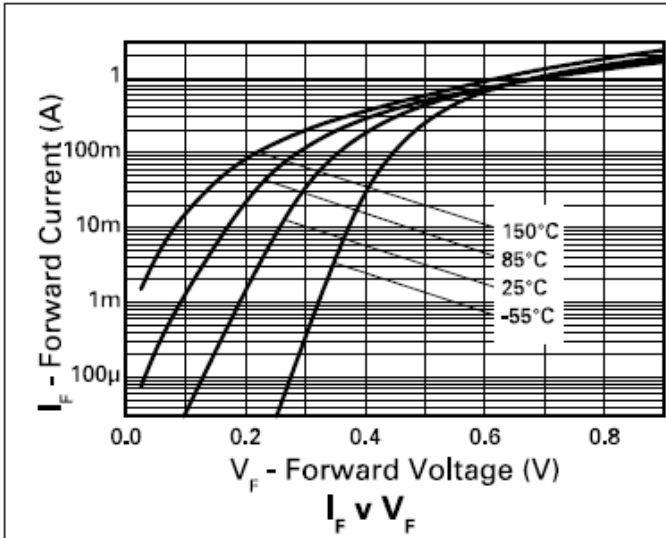
Electrical Characteristics @ $T_A = 25^\circ\text{C}$ unless otherwise specified

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
Reverse Breakdown Voltage	$V_{(BR)R}$	40	60	-	V	$I_R = 200\mu\text{A}$
Forward Voltage (Note 4)	V_F	-	305	360	mV	$I_F = 50\text{mA}$
		-	335	390		$I_F = 100\text{mA}$
		-	395	450		$I_F = 250\text{mA}$
		-	445	500		$I_F = 400\text{mA}$
		-	550	630		$I_F = 750\text{mA}$
		-	620	710		$I_F = 1\text{A}$
		-	710	800		$I_F = 1.5\text{A}$
		-	405	-		$I_F = 400\text{mA}, T_A = 100^\circ\text{C}$
Reverse Current	I_R	-	6	10	μA	$V_R = 30\text{V}$
		-	370	-	$V_R = 30\text{V}, T_A = 85^\circ\text{C}$	
Diode Capacitance	C_D	-	15	-	pF	$f = 1\text{MHz}, V_R = 30\text{V}$
Reverse Recovery Time	t_{rr}	-	3	-	ns	Switched from $I_F = 500\text{mA}$ to
Reverse Recovery Charge	Q_{rr}	-	210	-	pC	$V_R = 5.5\text{V}$ Measured @ $I_R = 50\text{mA}$ $di/dt = 500\text{mA/ns}$ $R_{source} = 6\Omega; R_{load} = 10\Omega$

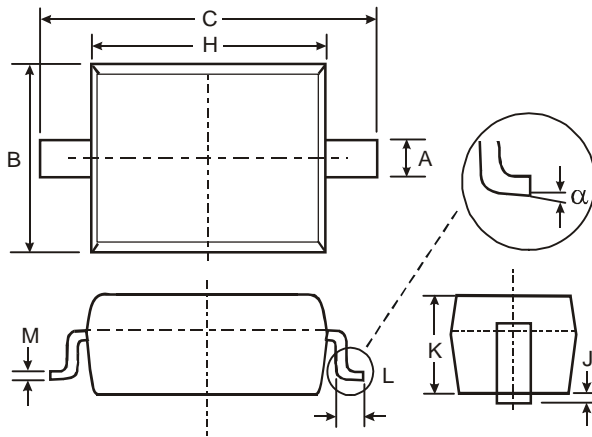
Notes: 4. Measured under pulsed conditions. Pulse width = 300 μs . Duty cycle = 2%.

Operational efficiency chart

Operational Efficiency Example

The operational efficiency chart indicates the beneficial use of the ZLLS series diodes in applications requiring higher voltage, higher temperature operation. Circuits requiring low voltage low temperature operation will benefit from using Zetex low V_F ZHCS series diodes.

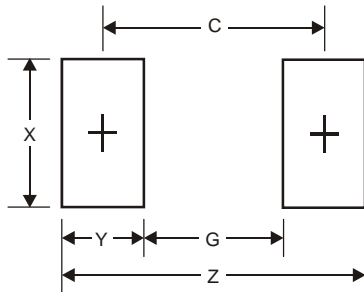


Package Outline Dimensions



SOD323		
Dim	Min	Max
A	0.25	0.35
B	1.20	1.40
C	2.30	2.70
H	1.60	1.80
J	0.00	0.10
K	1.0	1.1
L	0.20	0.40
M	0.10	0.15
α	0°	8°
All Dimensions in mm		

Suggested Pad Layout



Dimensions	Value (in mm)
Z	3.75
G	1.05
X	0.65
Y	1.35
C	2.40

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Офис по работе с юридическими лицами:

105318, г.Москва, ул.Щербаковская д.3, офис 1107, 1118, ДЦ «Щербаковский»

Телефон: +7 495 668-12-70 (многоканальный)

Факс: +7 495 668-12-70 (доб.304)

E-mail: info@moschip.ru

Skype отдела продаж:

moschip.ru

moschip.ru_4

moschip.ru_6

moschip.ru_9